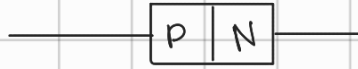
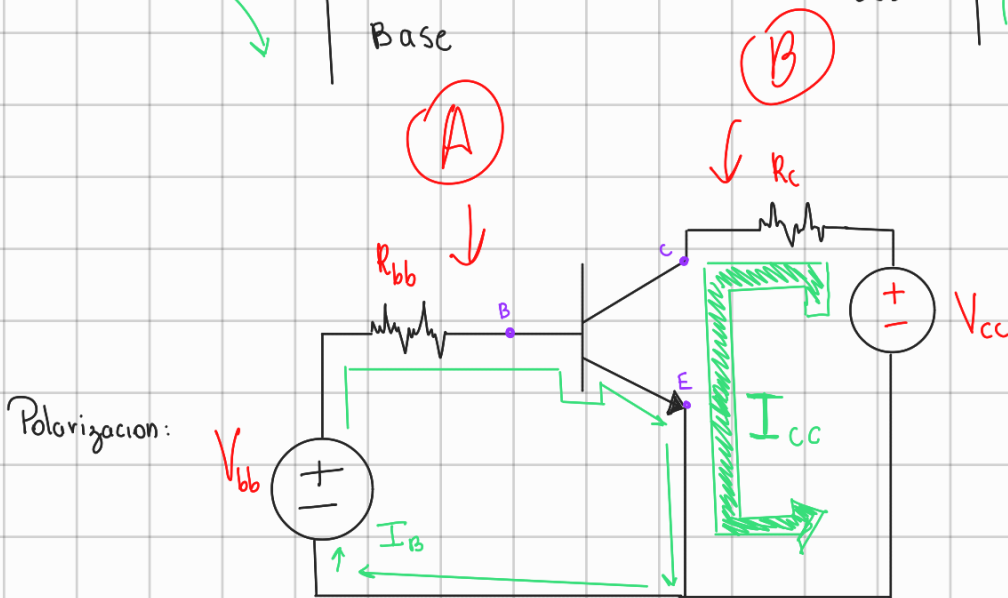
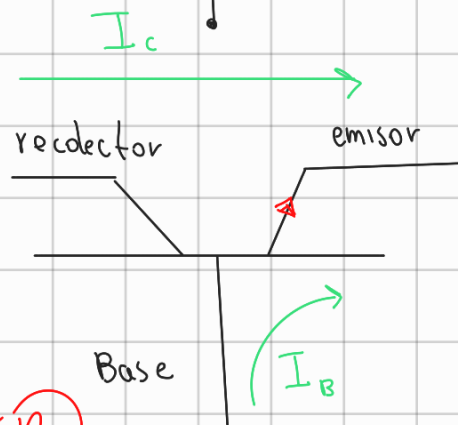
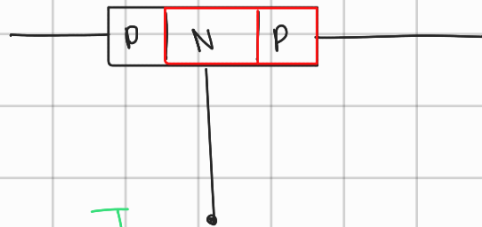
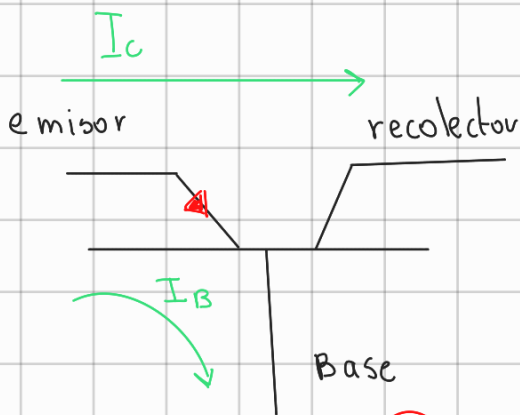
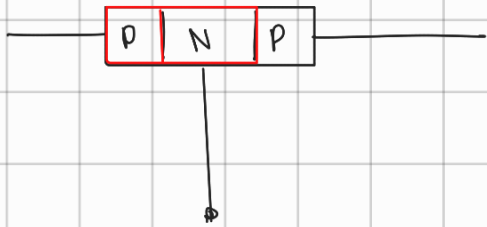


diodo



transistor (BJT):



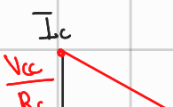
$$I_c = \beta I_B \quad \frac{I_c}{I_B} = \beta \quad \leftarrow \text{Ganancia}$$

$$I_e = I_B + I_c$$

(0,1)

$$\textcircled{A} \quad V_{BB} = I_B \cdot R_{bb} + V_{be}$$

$$\textcircled{B} \quad V_{CC} = R_c \cdot I_c + V_{ce}$$



β

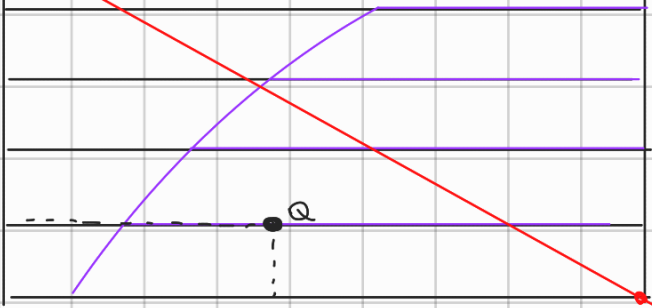
I_B

si $I_B = 0$

$$\Rightarrow I_c = \beta I_b \rightarrow I_c = 0$$

$$\text{Si } V_{ce} = 0$$

$$I_c = \frac{V_{ce}}{R_{cc}}$$



Q = punto de operación

V_{ce} Recta de carga

3 zonas

Curvas del transistor

